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(54)

2 ; ; 1 2 ; 1 2 ; 1 2 ; 1

1

2 1

3 2

4 1

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6 5

7 5 EL 1

8 7

9 5 EL 2

10 9

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10,20 : EL 12,22 :

14,24 : 16,26,36,46,56,66 : EL

28 :

(Cothode Ray Tube)
 (Liquid Crystal Display : " LCD"), (Field Emiss
 ion Display), (Plasma Display Panel : " PDP") (Ele
 ctro - Luminescence : " EL")
 EL
 , EL
 , EL

EL (DL1 DLn) , (PE) (10) (GL1 GLm) (DL1 DLn) (GL1 GLm)

DL) (PE) (GL1 GLn) (

EL (14)가 (DL1 DLn) (12)가 (GL1 GLm) (12) (GL1 GLm) (PE)

GLm) (14) (DL1 DLn) (16)

(GND) (12) EL (OLED) , EL (OLED) (PE) 2 (16)

2 1 (PE) (GL) (DL) (Thin Film Transistor ; " TFT" , T1,T2)

2 (PE) (GND) EL (OLED) , EL (OLED) (DL) EL (OLED) (16)

EL (OLED) (16) EL (OLED) (VDD) 2 PMOS S TFT(T2) ; (DL) 2 PMOS TFT(T2) EL (OLED) (VDD) 1 PMOS TFT(T1) ; 1 PMOS TFT(T1) (Cst)

12) 3 가 1 PMOS TFT(T1)가 (GL) (LOW) (

1 PMOS TFT(T1)가 (DL) 가 (Cst) (Cst) 1 PMOS TFT(T1) (VDD) (GL)

(Cst) (DL) (DL) 1 가 EL (OLED) (Holding) (Cst) (DL) 가 RGB 가

4 1 (PE) (GL) (DL) 4 TFT(T3, T4, T5, T6)

4 (PE) (GND) EL (OLED) , EL (OLED) (DL) EL (OLED) (26)

EL (26) EL (OLED), (VDD) 3 4 PMOS TFT(T3, T4) ; 4 PMOS TFT(T4), (DL) (GL) (GL) 5 PMOS TFT(T5) ; 3 PMOS TFT(T3) 4 PMOS TFT(T4) (GL) 5 PMOS TFT(T5) 6 PMOS TFT(T6); 3 PMOS TFT(T3) 4 PMOS TFT(T4) (VDD) (C_{ST})

T(T6) - (GL) (LOW) 가 5 PMOS TFT(T5) 6 PMOS TF
 (Cst) 5 PMOS TFT(T5) 6 PMOS TFT(T6)가 (DL) 6 PMOS TFT(T6)
 (Cst) (GL) 3 PMOS TFT(T3) 4 PMOS TFT(T4) (VDD)
 (Cst) (DL) (DL) 1 (Holding) (Cst)
 (DL) 가 RGB 가 EL (OLED) 가
 1 (Cst) EL (OLED)
 (DL) (PE) (14) (GL) (DL)
 ;
 ; 1 2 ; 1 2
 ; 1 2
 가 1 (VDD) ;
 가 1 ; 2 , 1 1
 2
 3
 가 , 1 2 (VDD) ;
 가 ;
 1 2 ; 1 2 , 3 3

가

5 10

5 EL

5 , EL (20) (GL1 GLm)

(DL1 DLn) , (GL1 GLm) (DL1 DLn)

(PE1, PE2) , (GL1 GLm) MUX (MUX1, MUX2)

(PE1, PE2) (DL) (GL1 GLm)

MUX (MUX1, MUX2) 가 (DL1 DLn)

EL (22)가 (GL1 GLm)

(24)가 (DL1 DLn) (28)가 MUX (MUX1, MUX2)

(22) (GL1 GLm)

(24) (DL1 DLn)

(PE1, PE2) (28) (28) 6 MU

X

6 , MUX (28) , (28)

2 가 MUX (MUX1, MUX2) (M1, M2) , MUX (M1, M2)

(22), (24) (28) (PE1, PE2)

7 (GND) EL (OLED) , EL (OLED)

(36,46)

7 5 EL 1

7 (DL) , 1 (PE1) EL (OLED) (GND) (36) EL (OLED) , EL (OLED)

EL (OLED) (36) EL (OLED), (VDD) EL (OLED)
 1 PMOS TFT(P1) ; (DL) 1 PMOS TFT(P1)
 2 PMOS TFT(P2) ; 2 PMOS TFT(P2) (DL) 3 PMOS
 S TFT(P3) ; 1 PMOS TFT(P1) (VDD) 1 (Cst1)

2 PMOS TFT(P2) (28) 1 MUX (MUX1) (GLn) , 3 PMOS TFT(P3)

2 (PE2) EL (OLED) (GND) (46) EL (OLED) , EL (OLED) (DL)
 EL (OLED)

EL (OLED) (46) EL (OLED), (VDD) EL (OLED)
 4 PMOS TFT(P4) ; (DL) 4 PMOS TFT(P4)
 4 PMOS TFT(P4) ; 5 PMOS TFT(P5) (DL) 6 PMOS
 S TFT(P6) ; 4 PMOS TFT(P4) (VDD) 2 (Cst2)

5 PMOS TFT(P5) (28) 2 MUX (MUX2) (GLn) , 6 PMOS TFT(P6)

8 W) 가 1 MUX (MUX1) (LOW) 가 TFT(P3) 1
 2 PMOS TFT(P2)가 1 MUX (MUX1) (LOW) 가
 7 가 (GLn) 2 (LO (M1)가 3 PMOS

1 (Cst1) (DL) (DL) 가 EL (OLED) (Holding) 1
 (Cst1)

1 MUX (MUX1) (LOW) 가 (MUX2) (LOW) 가 2 MUX (M2)가 6 PMOS TFT(P6) 1
 3 PMOS TFT(P3) 1 2 MUX

(GL) 2 MUX (MUX2) 가 5 PMOS TFT(P5) 6 PMOS TF
 T(P6)가

, 5 PMOS TFT(P5) 6 PMOS TFT(P6)가 (DL)
 가 5 PMOS TFT(P5) 6 PMOS TFT(P6) , 2 (C
 st2) . 2 (Cst2) 4 PMOS TFT(P4) (VDD)
 (GLn) 2 MUX (MUX2) 가 (DL)

2 (Cst2) (DL) 1 (Holding)
 . (DL) 가 EL (OLED) 2
 (Cst2)

9 5 EL 2 ()
 GL) (DL) 4 TFT .

9 , 1 (PE1) (GND) EL (OLED) , EL (OLED)
 (DL) EL (OLED) (56)

EL (OLED) (56) EL (OLED), (VDD)
 7 PMOS TFT(P7) 8 PMOS TFT(P8) ; 8 PMOS TFT(P8), (DL) (GL)
 (GL) 9 PMOS TFT(P9) ; 7 PMOS TFT(P7)
 8 PMOS TFT(P8) , 1 MUX (MUX1) 9 PMOS TFT(P9)
 10 PMOS TFT(P10) ; 7 PMOS TFT(P7) 8 PMOS TFT(P8) (VDD)
 3 (Cst3)

2 (PE2) (GND) (OLED) , EL (OLED) (DL)
 EL (OLED) (66)

EL (OLED) (66) EL (OLED), (VDD)
 11 PMOS TFT(P11) 12 PMOS TFT(P12) ; 12 PMOS TFT(T12), (DL)
 (GL) 13 PMOS TFT(P13) ; 11 PMOS TFT
 (P11) 12 PMOS TFT(P12) , 2 MUX (MUX2) 13 PMOS TFT(P13)
 14 PMOS TFT(P14); 11 PMOS TFT(P11) 12 PMOS TFT(P12)
 (VDD) 4 (Cst4)

10 가 9 9 PMOS TFT(P9)가 - , n (GLn) 2 (L
 가2 가 n+1 (GLn+1) (High)

(28) 1 MUX (M1)가 1 MUX (MUX1) (LOW) 가
 . 1 MUX (MUX1) (LOW) 가 10 PMOS TFT(P10) 1 -

, 9 PMOS TFT(P9) 10 PMOS TFT(P10)가 (DL)
 가 , 3 (Cst3)

3 (Cst3) (DL) 1 (Holding)
 (Cst1) . 1 (DL) 가 EL (OLED) 3 EL (OLED)

1 MUX (MUX1) (LOW) 가 10 PMOS TFT (P10) 1
 (MUX2) (LOW) 가 2 MUX (M2)가 2 MUX (M2)가 2 MUX
 14 PMOS TFT (P14) 1

(GLn) 2 MUX (MUX2) 가 13 PMOS TFT (P13) 14 P
 MOS TFT (P14)가 (DL) 가 ,
 4 (Cst4)

4 (Cst4) (DL) 1 (Holding)
 (Cst1) (DL) 가 EL (OLED) 3

MUX

가

(57)

1.

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1 2

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1 2

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1 2

2.

1 ,

7.

6

2

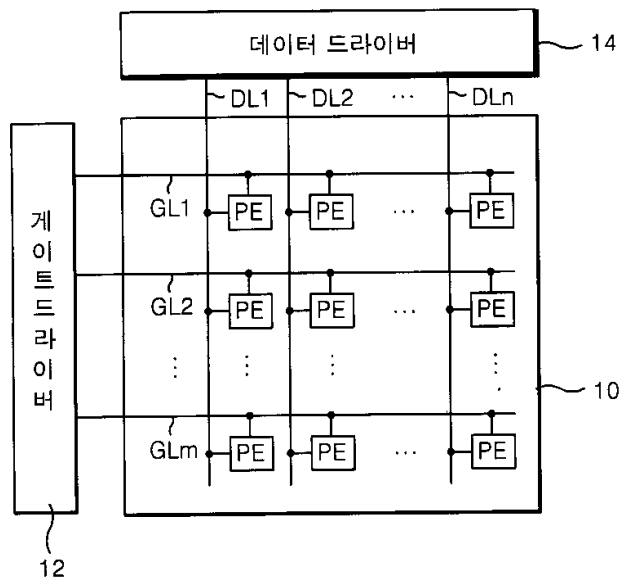
8.

6

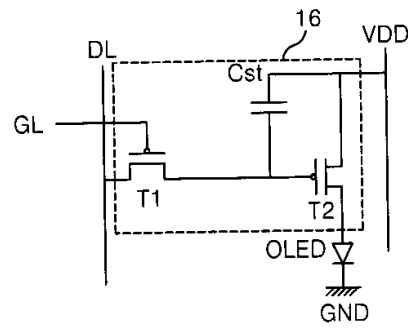
가

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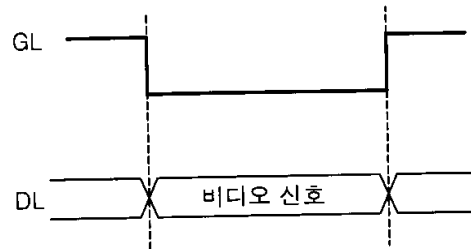
1



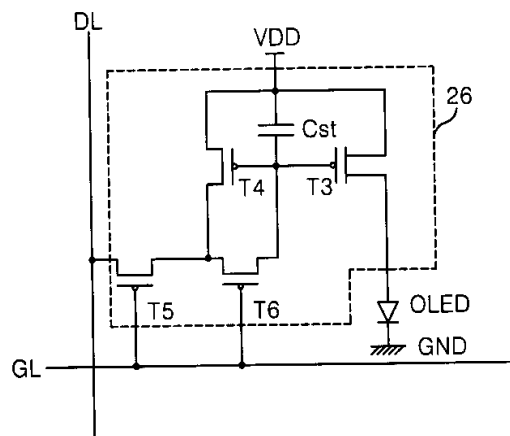
2



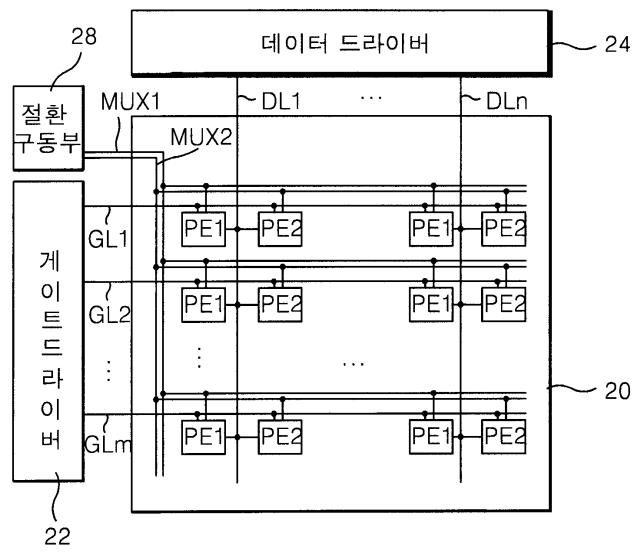
3



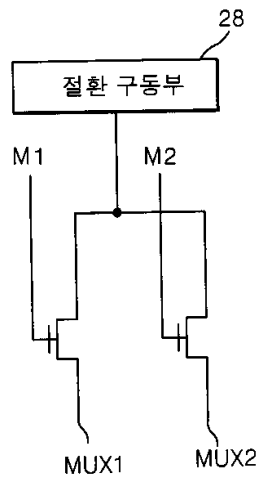
4



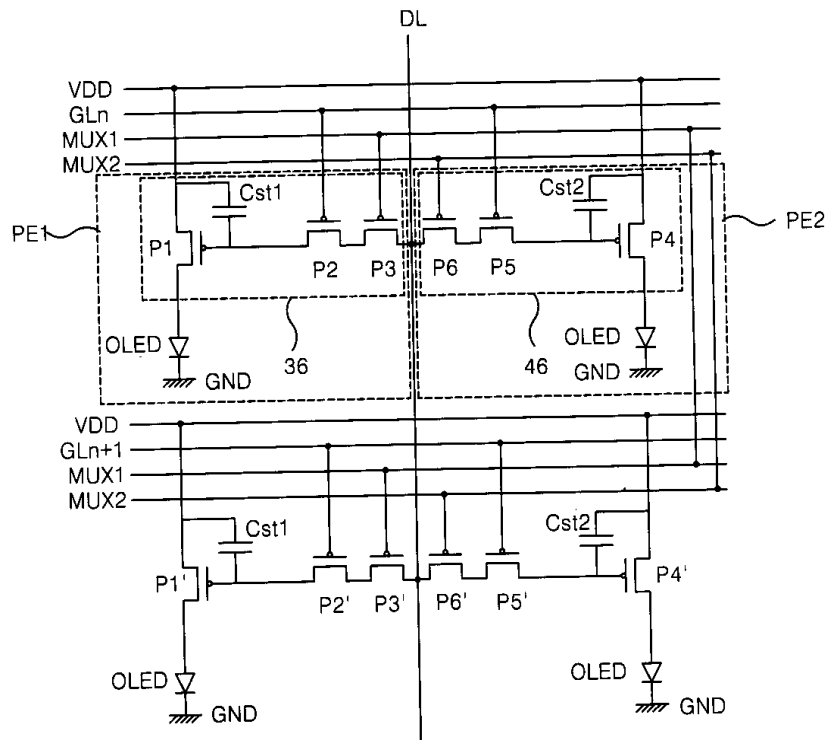
5



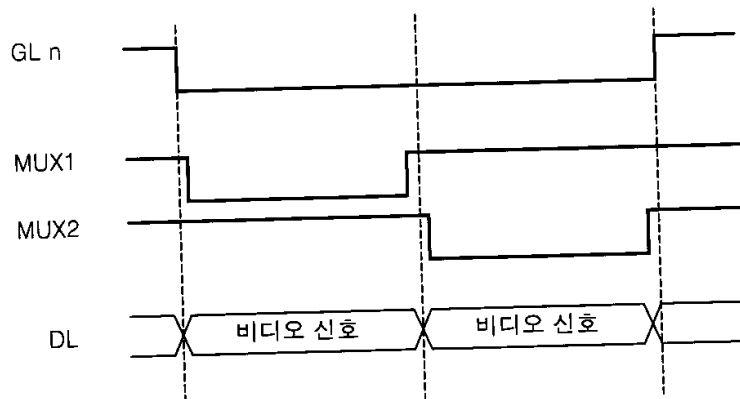
6

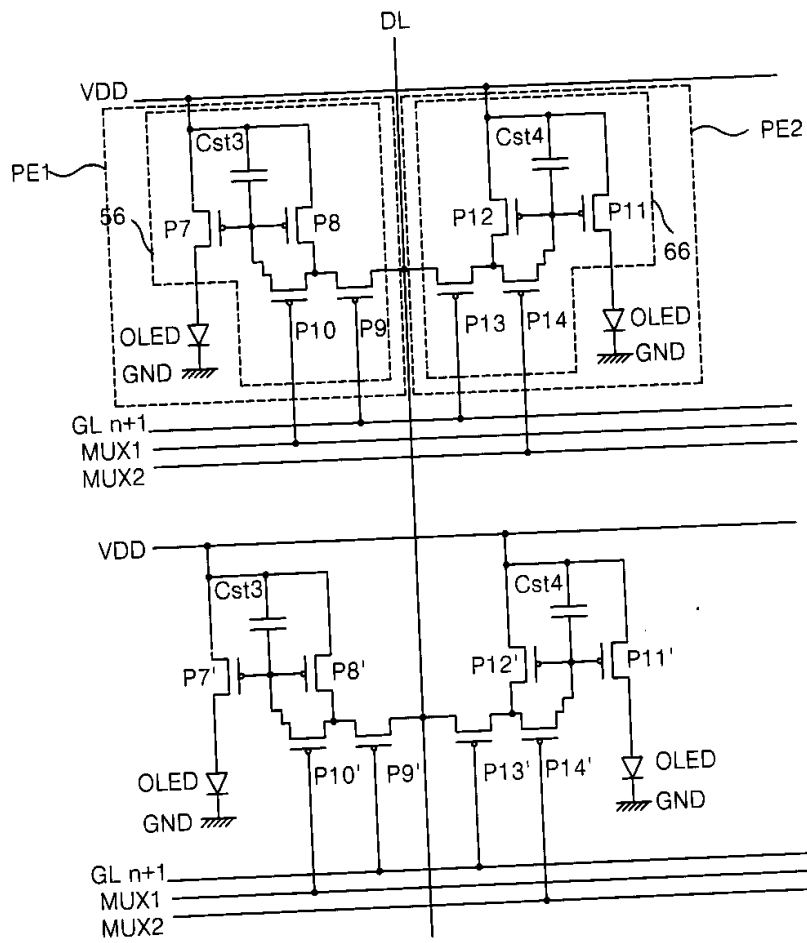


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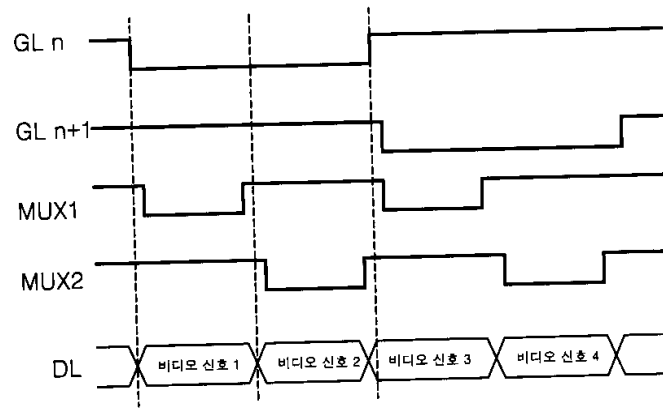


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专利名称(译)	电致发光面板及其驱动方法		
公开(公告)号	KR1020020087238A	公开(公告)日	2002-11-22
申请号	KR1020010026309	申请日	2001-05-15
[标]申请(专利权)人(译)	乐金显示有限公司		
申请(专利权)人(译)	LG显示器有限公司		
当前申请(专利权)人(译)	LG显示器有限公司		
[标]发明人	PARK JOON KYU 박준규 LEE HANSANG 이한상		
发明人	박준규 이한상		
IPC分类号	G09G3/30		
代理人(译)	KIM , YOUNG HO		
其他公开文献	KR100743102B1		
外部链接	Espacenet		

摘要(译)

电致发光面板及其驱动方法技术领域本发明涉及一种电致发光面板，更具体地，涉及一种电致发光面板及其驱动方法，其中减少了数据线和数据驱动器的数量。 根据本发明的电致发光面板包括多条栅极线；多条数据线布置成与栅极线交叉；第一和第二电致发光单元设置在栅极线和数据线相对于数据线的交叉的两侧；在第一和第二电致发光单元中的每一个中提供单元驱动装置，用于响应于数据线上的信号控制从电致发光单元辐射的光量；以及用于选择性地驱动第一和第二电致发光单元的开关驱动器。 根据本发明，电致发光面板可以通过将多路复用器电路应用于栅极线来驱动一条数据线上的双向像素。结果，可以减少数据线的数量，并且可以减少与数据线的数量相对应的数据驱动器的数量，从而实现成本降低。 五 - 1 -

